

## **Active Bias Controller**

### Characteristics

- Supplies stable bias current even at low battery voltage and extreme ambient temperature variatior
- Low voltage drop of 0.7V

### **Application notes**

- Stabilizing bias current of NPN transistors and FET's from less than 0.2mA up to more than 200mA
- Ideal supplement for Sieget and other transistors
- also usable as current source up to 5mA
- Pb-free (RoHS compliant) package<sup>1)</sup>
- Qualified according AEC Q101



Туре	Marking	Pin Configuration			Package	
BCR400W	W4s	1=GND/ <b>E</b> <sub>NPN</sub>	2=Contr/ <b>B</b> <sub>NPN</sub>	3V <sub>S</sub>	4=Rext/ <b>C</b> <sub>NPN</sub>	SOT343

(E<sub>NPN</sub>, B<sub>NPN</sub>, C<sub>NPN</sub> are electrodes of a stabilized NPN transistor)

### **Maximum Ratings**

Parameter	Symbol	Value	Unit
Source voltage	V <sub>S</sub>	18	V
Control current	I <sub>Contr.</sub>	10	mA
Control voltage	V <sub>Contr.</sub>	16	V
Reverse voltage between all terminals	V <sub>R</sub>	0.5	
Total power dissipation, $T_{\rm S}$ = 117 °C	P <sub>tot</sub>	330	mW
Junction temperature	Tj	150	°C
Storage temperature	T <sub>stg</sub>	-65 150	

#### **Thermal Resistance**

	Junction - soldering point <sup>2)</sup>	R <sub>thJS</sub>	≤ 100	K/W
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<sup>1</sup>Pb-containing package may be available upon special request

<sup>2</sup>For calculation of  $R_{thJA}$  please refer to Application Note Thermal Resistance





**BCR400W** 



Parameter	Symbol	Values			Unit
		min.	typ.	max.	
DC Characteristics					
Additional current consumption	I <sub>0</sub>	-	20	40	μA
$V_{\rm S} = 3 \text{ V}$					
Lowest stabilizing current	I <sub>min</sub>	-	0.1	-	mA
V <sub>S</sub> = 3 V					
DC Characteristics with stabilized NPN-T	ransistors				
Lowest sufficient battery voltage	V <sub>Smin</sub>	-	1.6	-	V
<i>I</i> <sub>B</sub> (NPN) < 0.5mA					
Voltage drop (V <sub>S</sub> - V <sub>CE</sub> )	V <sub>drop</sub>	-	0.65	-	
<i>I</i> <sub>C</sub> = 25 mA					
Change of I <sub>C</sub> versus h <sub>FE</sub>	$\Delta I_{\rm C}/I_{\rm C}$	-	0.08	-	$\Delta h_{\rm FE}$ /
h <sub>FE</sub> = 50					h <sub>FE</sub>
Change of $I_{\rm C}$ versus $V_{\rm S}$	$\Delta I_{\rm C}/I_{\rm C}$	-	0.15	-	$\Delta V_{\rm S}/V_{\rm S}$
V <sub>S</sub> = 3 V					
Change of $I_{\rm C}$ versus $T_{\rm A}$	$\Delta I_{\rm C}/I_{\rm C}$	-	0.2	-	%/K

# **Electrical Characteristics** at $T_A$ =25°C, unless otherwise specified



## **Collector current** $I_{\rm C} = f(h_{\rm FE})$

 $I_{\rm C}$  and  $h_{\rm FE}$  refer to stabilized NPN Transistor Parameter  $R_{\rm ext.}$  ( $\Omega$ )



Collector Current  $I_{\rm C} = f(V_{\rm S})$ 

of stabilized NPN Transistor Parameter  $R_{ext.}$  ( $\Omega$ )



Voltage drop  $V_{drop} = f(I_C)$ 



**Collector current**  $I_{\rm C} = f(R_{\rm ext.})$ of stabilized NPN Transistor





# **Collector current** $T_A = f(I_C)$

of stabilized NPN Transistor Parameter:  $R_{ext}(\Omega)$ 10 <sup>3</sup> mΑ 2.2 6 10<sup>2</sup> 26 2 65 10<sup>1</sup> 290 760 10<sup>0</sup> 4.3k 10 °C -40 -20 0 20 40 60 80 100 120 160  $T_A$ 

# **Control current** $I = f(R_{ext.})$

in current source application



**Control current**  $I = f(T_A)$ 

in current source application



**Control current**  $I = f(V_S)$ in current source application





# Total power dissipation $P_{tot} = f(T_S)$



Note that up to  $T_S$ =115°C it is not possible to exceed  $P_{tot}$ respecting the maximum ratings of  $V_S$  and  $I_{Contr.}$ The collector or drain current (respectively) of the stabilized RF transistor does not affect BCR 400 directly, as it provides just the base current.

# Typical application for GaAs FET with active bias controller





### **RF transistor controlled by BCR400**



Be aware that BCR400 stabilized bias current of transistors in an active control loop

In order to avoid loop ascillation (hunting), time constants must be chosen adequately, i.e. **C1 >= 10 x C2** 

RX/TX antenna switch, compatible to control logic and working at wide battery voltage range





### Low voltage reference



Precision timer with BCR400 providing constant charge current







## Foot Print



## Marking Layout (Example)



# Standard Packing

Reel ø180 mm = 3.000 Pieces/Reel Reel ø330 mm = 10.000 Pieces/Reel





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